

iscN-Channel MOSFET Transistor
TK8P25DA
• FEATURES

- Low drain-source on-resistance:
 $R_{DS(ON)} = 0.5\Omega$ (MAX)
- Enhancement mode:
 $V_{th} = 1.5$ to $3.5V$ ($V_{DS} = 10V$, $I_D = 1.0mA$)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

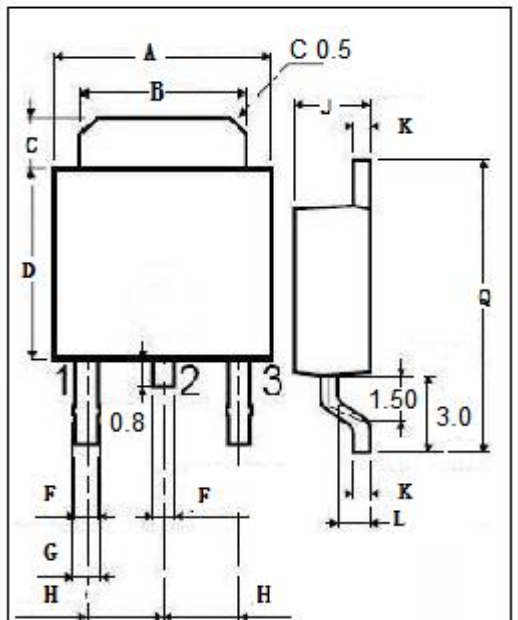
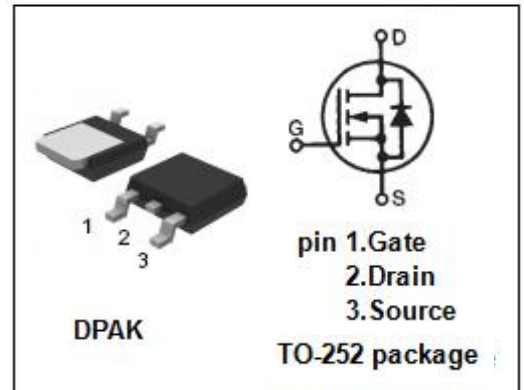
- Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	250	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous	7.5	A
I_{DM}	Drain Current-Single Pulsed	30	A
P_D	Total Dissipation @ $T_c = 25^\circ C$	55	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	2.27	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
F	0.65	
G	0.75	
H	2.10	2.50
J	2.10	2.40
K	0.40	0.60
L	0.90	1.10
Q	9.90	10.1

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ELECTRICAL CHARACTERISTICS

T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	250			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = 10V; I _D =1.0mA	1.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =3.8A			500	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =250V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =7.5A, V _{GS} = 0 V			1.7	V

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